

## STLVDS050

# HIGH SPEED DIFFERENTIAL LINE DRIVERS AND RECEIVERS

- MEETS OR EXCEED THE REQUIREMENTS OF ANSI EIA/TIA-644-1995 STANDARD
- SIGNALING RATES UP TO 400Mbit/s
- BUS TERMINAL ESD EXCEEDS 6KV
- OPERATES FROM A SINGLE 3.3V SUPPLY
- LOW-VOLTAGE DIFFERENTIAL SIGNALING WITH TYPICAL OUTPUT VOLTAGE OF 350mV AND A 100Ω LOAD
- PROPAGATION DELAY TIMES:

DRIVER: 2ns (TYP) RECEIVER: 3ns (TYP)

■ POWER DISSIPATION AT 200MHz:

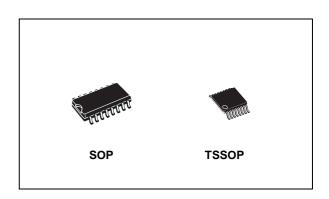
DRIVER: 25mW (TYP) RECEIVER: 60mW (TYP)

- LVTTL INPUT LEVELS ARE 5V TOLERANT
- RECEIVER HAS OPEN-CIRUIT FAIL-SAFE



The STLVDS050 is differential line drivers and receivers that use low-voltage differential signaling (LVDS) to achieve signaling rate as high as 400Mbps.

The EIA/TIA-644 standard compliant electrical interface provides a minimum differential output voltage magnitude of 247 mV into a 100  $\Omega$  load and receipt of 100 mV signals with up to 1 V of



ground potential difference between a transmitter and receiver.

The intended application of this device an signaling technique is for point-to-point baseband data transmission over controlled impedance media of approximately 100  $\Omega$  characteristic impedance.

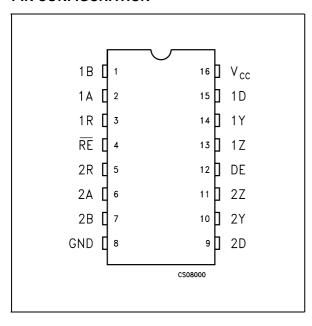
The transmission media may be printed-circuit board traces, backplanes, or cables. (Note: The ultimate rate and distance of data transfer is dependent upon the attenuation characteristics of the media, the noise coupling to the environment, and other application specific characteristics).

#### **ORDERING CODES**

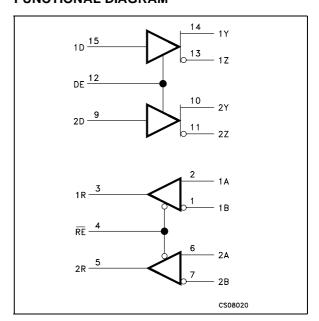
Туре	Temperature Range	Package	Comments
STLVDS050BD	-40 to 85 °C	SO-16 (Tube)	50 parts per tube / 20 tube per box
STLVDS050BDR	-40 to 85 °C	SO-16 (Tape & Reel)	2500 parts per reel
STLVDS050BTR	-40 to 85 °C	TSSOP16 (Tape & Reel)	2500 parts per reel

February 2003 1/11

### **PIN CONFIGURATION**



### **FUNCTIONAL DIAGRAM**



### **PIN DESCRIPTION**

PIN N°	SYMBOL	NAME AND FUNCTION
1,2, 6, 7	1A, 1B, 2A, 2B	Receiver Inputs
3, 5	1R, 2R	Receiver Outputs
4	RE	Receiver Enable
9, 15	2D, 1D	Driver Inputs
12	DE	Driver Enable
10, 11, 13, 14	2Y, 2Z, 1Y, 1Z	Driver Outputs
8	GND	Ground
16	V <sub>CC</sub>	Supply Voltage

### TRUTH TABLE FOR RECEIVER

V <sub>ID</sub> =V <sub>A</sub> -V <sub>B</sub>	RE	R
V <sub>ID</sub> ≥ 100mV	L	Н
-100mV < V <sub>ID</sub> < 100mV	L	?
$V_{ID} \le -100 mV$	L	L
OPEN	L	Н
X	Н	Z

### TRUTH TABLE FOR DRIVER

D	DE	Y	Z
L	Н	L	Н
Н	Н	Н	L
OPEN	Н	L	Н
Х	L	Z	Z

L=Low level, H=High Level, X=Don't care, Z= High Impedance

### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter		Value	Unit
V <sub>CC</sub>	Supply Voltage		-0.5 to 4	V
VI	Voltage Range	D, R, DE, RE	-0.5 to 6	V
ESD	ESD Protection Voltage (HBM)	Y, Z, A, B, and GND	± 6	ΚV
		All Pins	± 3	ΓV
T <sub>stg</sub>	Storage Temperature Range		-65 to +150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min.	Тур.	Max.	Unit
V <sub>CC</sub>	Supply Voltage	3.0	3.3	3.6	V
V <sub>IH</sub>	HIGH Level Input Voltage	2.0			V
$V_{IL}$	LOW Level Input Voltage			0.8	V
V <sub>ID</sub>	Magnitude Of Differential Input Voltage	0.1		0.6	V
V <sub>IC</sub>	Common Mode Input Voltage	V <sub>ID</sub>  /2		24- V <sub>ID</sub>  /2	V
				V <sub>CC</sub> -0.8	
T <sub>A</sub>	Operating Temperature Range	-40		85	°C

## **ELECTRICAL CHARACTERISTICS** (Typical values are at $T_A$ = 25°C, $V_{CC}$ = 3.3V ±10%, $T_A$ = -40 to 85°C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I <sub>CC</sub>	Supply Current	Drivers and Receivers enabled, No receiver loads, Driver $R_L$ =100 $\Omega$		12	20	mA
		Driver enabled, Receivers disabled, $R_L \! = \! 100\Omega$		10	16	
		Drivers Disabled, Receiver enabled, No load		4	6	
		Disabled		0.5	1	

# **DRIVER ELECTRICAL CHARACTERISTICS** (Typical values are at $T_A = 25$ °C, $V_{CC} = 3.3 V \pm 10\%$ , $T_A = -40$ to 85°C unless otherwise specified)

Symbol	Parameter	Test Conditio	ns	Min.	Тур.	Max.	Unit
V <sub>OD</sub>	Differential Output Voltage Magnitude	$R_L = 100\Omega$		247	350	454	mV
Δ V <sub>OD</sub>	Change in Differential Output Voltage Magnitude Between Logic States	$R_L = 100\Omega$		-25		25	mV
$\Delta V_{OC(SS)}$	Change in Steady-state Common Mode Output Voltage Between Logic States			-25		25	mV
V <sub>OC(SS)</sub>	Steady-state Common Mode Output Voltage			1.125	1.2	1.375	V
V <sub>OC(PP)</sub>	Peak to Peak Common mode Output Voltage				50	150	mV
I <sub>IH</sub>	High Level Input Current	V <sub>IH</sub> = 5V	DE		-0.5	-20	μΑ
			D		2	20	μΑ
I <sub>IL</sub>	Low Level Input Current	$V_{IL} = 0.8V$	DE		-0.5	-10	μΑ
			D		1	10	μΑ
Ios	Short Circuit Output Current	$V_{O(Y)}$ or $V_{O(Z)} = 0V$			6	10	mA
		V <sub>OD</sub> = 0			4	10	mA
I <sub>OZ</sub>	High Impedance Output	V <sub>O</sub> = 600mV				± 1	μΑ
	Current	$V_O = 0V \text{ or } V_{CC}$				± 1	μΑ
I <sub>O(OFF)</sub>	Power OFF Output Current	$V_{CC} = 0V$ $V_O = 3.6V$				± 1	μΑ
C <sub>IN</sub>	Input Capacitance				3		pF

# **RECEIVER ELECTRICAL CHARACTERISTICS** (Typical values are at $T_A$ = 25°C, $V_{CC}$ = 3.3V ±10%, $T_A$ = -40 to 85°C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V <sub>ITH+</sub>	Positive-going Differential Input Voltage Threshold				100	mV
V <sub>ITH-</sub>	Negative-going Differential Input Voltage Threshold		-100			mV
V <sub>OH</sub>	High Level Output Voltage	$I_{OH} = -8mA$	2.4			V
V <sub>OL</sub>	Low Level Output Voltage	I <sub>OL</sub> = 2mA			0.4	V
l <sub>l</sub>	Input Current (A or B Inputs)	V <sub>I</sub> =0V	-2	-11	-20	μΑ
		V <sub>I</sub> = 2.4V	-1	-3		μΑ
I <sub>I(OFF)</sub>	Power OFF Input Current (A or B Inputs)	V <sub>CC</sub> = 0V			±20	μΑ
I <sub>IH</sub>	High Level Input Current (Enable)	V <sub>IH</sub> = 5V			±10	μΑ
I <sub>IL</sub>	Low Level Input Current (Enable)	$V_{IL} = 0.8V$			±10	μΑ
l <sub>OZ</sub>	High Impedance Output Current	$V_O = 0 \text{ or } 5V$			± 10	μΑ
C <sub>IN</sub>	Input Capacitance			3		pF

# **DRIVER SWITCHING CHARACTERISTICS** (Typical values are at $T_A$ = 25°C, $V_{CC}$ = 3.3V ±10%, $T_A$ = -40 to 85°C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
t <sub>PLH</sub>	Propagation Delay Time, Low to High Output	$R_L = 100\Omega$ $C_L = 10pF$		2	2.7	ns
t <sub>PHL</sub>	Propagation Delay Time, High to Low Output			2	2.7	ns
t <sub>r</sub>	Differential Output Signal Rise Time			0.4	1	ns
t <sub>f</sub>	Differential Output Signal Fall Time			0.4	1	ns
t <sub>sk(P)</sub>	Pulse Skew ( t <sub>THL</sub> - t <sub>TLH</sub>  ) (note1)			50		ns
t <sub>sk(O)</sub>	Channel-to-channel Output Skew (note2)			40		ns
t <sub>PZH</sub>	Propagation Delay Time, High Impedance to High Level Output			6	10	ns
t <sub>PZL</sub>	Propagation Delay Time, High Impedance to Low Level Output			6	10	ns
t <sub>PHZ</sub>	Propagation Delay Time, High Level to High Impedance Output			3	10	ns
t <sub>PLZ</sub>	Propagation Delay Time, Low Level to High Impedance Output			3	10	ns

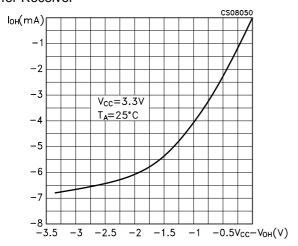
**RECEIVER SWITCHING CHARACTERISTICS** (Typical values are at  $T_A$  = 25°C,  $V_{CC}$  = 3.3V ±10%,  $T_A$  = -40 to 85°C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
t <sub>PLH</sub>	Propagation Delay Time, Low to High Output	C <sub>L</sub> = 10pF		3.0	4.0	ns
t <sub>PHL</sub>	Propagation Delay Time, High to Low Output			3.0	4.0	ns
t <sub>r</sub>	Differential Output Signal Rise Time			0.6	1	ns
t <sub>f</sub>	Differential Output Signal Fall Time			0.6	1	ns
t <sub>sk(P)</sub>	Pulse Skew ( t <sub>THL</sub> - t <sub>TLH</sub>  ) (Note 1)			0.25		ns
t <sub>PZH</sub>	Propagation Delay Time, High Impedance to High Level Output			2.5		ns
t <sub>PZL</sub>	Propagation Delay Time, High Impedance to Low Level Output			2.5		ns
t <sub>PHZ</sub>	Propagation Delay Time, High Level to High Impedance Output			7		ns
t <sub>PLZ</sub>	Propagation Delay Time, Low Level to High Impedance Output			4		ns

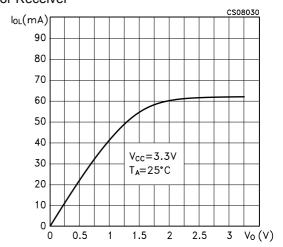
Note 1:  $t_{sk(P)}$  is the magnitude of the time difference between the high to low and low to high propagation delay times at an output Note 2:  $t_{sk(P)}$  is the magnitude of the time difference between the output of a single device with all their inputs connected together. Note 3:  $t_{sk(PP)}$  is the magnitude of the difference between any specified terminals of two devices when both devices operate with the same supply voltages, same temperature, and have identical packages and test circuit.

### TYPICAL PERFORMANCE CHARACTERISTICS (unless otherwise specified $T_J = 25$ °C)

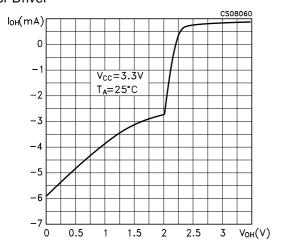
**Figure 1 :** Output Current vs Output High Voltage for Receiver



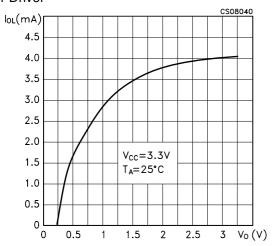
**Figure 2 :** Output Current vs Output Low Voltage for Receiver



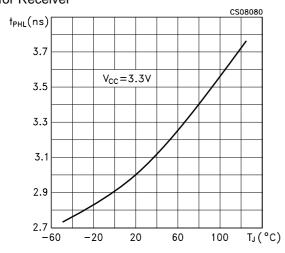
**Figure 3 :** Output Current vs Output High Voltage for Driver



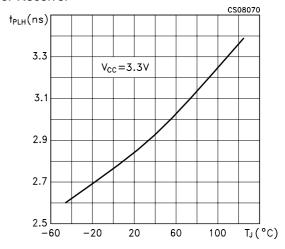
**Figure 4 :** Output Current vs Output Low Voltage for Driver



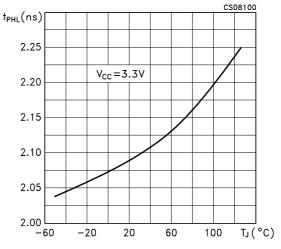
**Figure 5**: High to Low Propagation Delay Time for Receiver



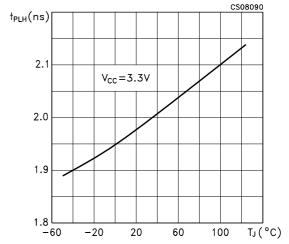
**Figure 6 :** Low to High Propagation Delay Time for Receiver



**Figure 7 :** High to Low Propagation Delay Time for Driver

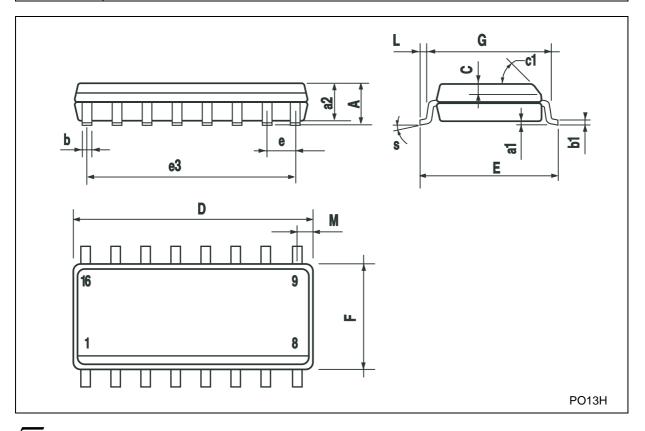


**Figure 8 :** Low to High Propagation Delay Time for Driver



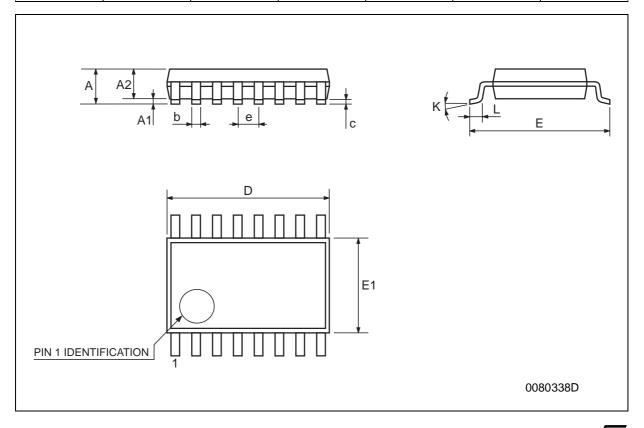
### **SO-16 MECHANICAL DATA**

DIM		mm.			inch	
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
Α			1.75			0.068
a1	0.1		0.2	0.004		0.008
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
С		0.5			0.019	
c1			45°	(typ.)		
D	9.8		10	0.385		0.393
Е	5.8		6.2	0.228		0.244
е		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.62			0.024
S	8		° (r	nax.)		



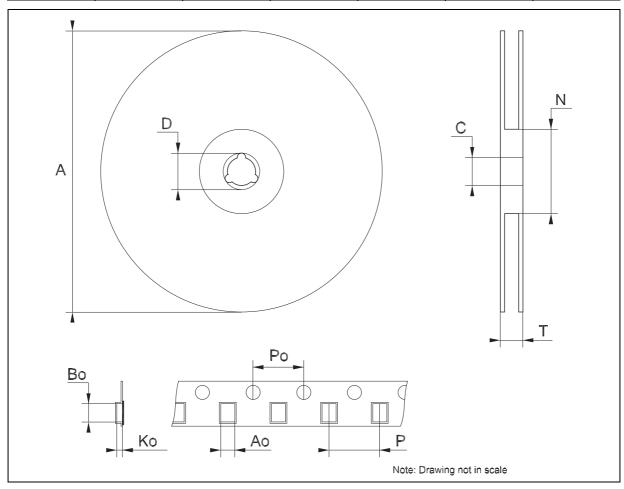
### **TSSOP16 MECHANICAL DATA**

DIM.	mm.			inch			
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А			1.2			0.047	
A1	0.05		0.15	0.002	0.004	0.006	
A2	0.8	1	1.05	0.031	0.039	0.041	
b	0.19		0.30	0.007		0.012	
С	0.09		0.20	0.004		0.0079	
D	4.9	5	5.1	0.193	0.197	0.201	
E	6.2	6.4	6.6	0.244	0.252	0.260	
E1	4.3	4.4	4.48	0.169	0.173	0.176	
е		0.65 BSC			0.0256 BSC		
K	0°		8°	0°		8°	
L	0.45	0.60	0.75	0.018	0.024	0.030	

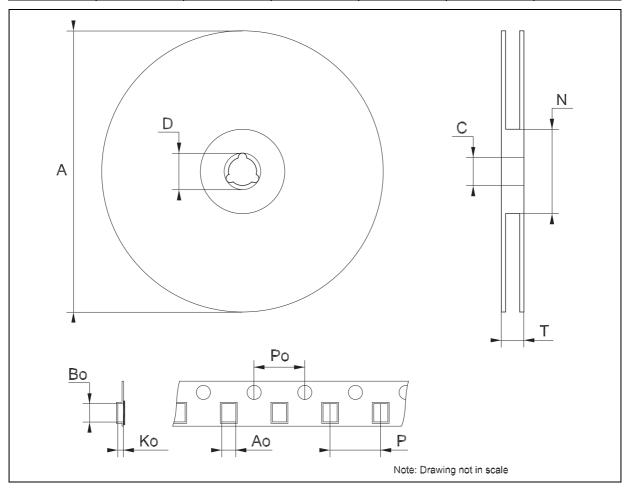


### Tape & Reel SO-16 MECHANICAL DATA

DIM.	mm.			inch			
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А			330			12.992	
С	12.8		13.2	0.504		0.519	
D	20.2			0.795			
N	60			2.362			
Т			22.4			0.882	
Ao	6.45		6.65	0.254		0.262	
Во	10.3		10.5	0.406		0.414	
Ko	2.1		2.3	0.082		0.090	
Po	3.9		4.1	0.153		0.161	
Р	7.9		8.1	0.311		0.319	



DIM.	mm.			inch			
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А			330			12.992	
С	12.8		13.2	0.504		0.519	
D	20.2			0.795			
N	60			2.362			
Т			22.4			0.882	
Ao	6.7		6.9	0.264		0.272	
Во	5.3		5.5	0.209		0.217	
Ko	1.6		1.8	0.063		0.071	
Ро	3.9		4.1	0.153		0.161	
Р	7.9		8.1	0.311		0.319	



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